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Dated: July 9, 2004

Signature: 

(Andrew T. Zidel)

Docket No.: 2003P51718US
INTECH 3.0-104
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Moritz Haupt

Application No.: 10/766,053

Group Art Unit: 2812

Filed: January 28, 2004

Examiner: Not Yet Assigned

For: METHOD FOR N+ DOPING OF
AMORPHOUS SILICON AND POLYSILICON
ELECTRODES IN DEEPTRENCHES

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. § 1.97 (b)

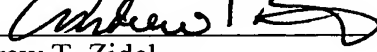
Dear Sir:

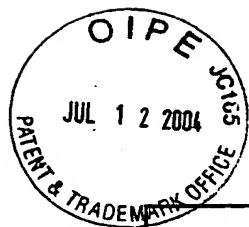
It is respectfully requested that the references listed on the enclosed form be made of record and considered with respect to the above-referenced U.S. patent application. Copies of non-patent literature documents are enclosed. Submission of the present Information Disclosure Statement should not be taken as an admission that the cited references are legally available prior art or that the same are pertinent or material.

In the event that any fee is due in connection with the present Information Disclosure Statement, the Commissioner is hereby authorized to charge the same to our Deposit Account No. 12-1095.

Dated: July 9, 2004

Respectfully submitted,

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PTO/SB/08a/b (08-03)

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Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	10/766,053
				Filing Date	January 28, 2004
				First Named Inventor	Moritz Haupt
				Art Unit	2812
				Examiner Name	Not Yet Assigned
Sheet	1	of	1	Attorney Docket Number	2003P51718US INTECH 3.0-104

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	AA	US-2003/0129798 A1	07/10/2003	Saenger et al.	
	AB	US-5,866,472	02/02/1999	Moslehi	
	AC	US-5,945,704	08/31/1999	Schrems et al.	
	AD	US-6,413,844 B1	07/02/2002	Beulens et al.	
	AE	US-6,528,384 B2	03/04/2003	Beckmann et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code ³	Number ⁴ -Kind Code ⁵ (if known)			

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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	CA	C. M. Ransom et al. "Shallow n+ Junctions in Silicon by Arsenic Gas-Phase Doping", J. Electrochem Soc., Vol. 141, No. 5, May 1994, pgs. 1378-1381	

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